

# **PMF63UNE** 20 V, N-channel Trench MOSFET 20 April 2016

Product data sheet

### 1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a very small SOT323 (SC-70) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

### 2. Features and benefits

- Trench MOSFET technology
- Low threshold voltage
- ElectroStatic Discharge (ESD) protection > 2 kV HBM

### 3. Applications

- LED driver
- Power management
- Low-side loadswitch
- Switching circuits

### 4. Quick reference data

| Table 1. Quie          | ck reference data                |  |     |     |     |     |      |
|------------------------|----------------------------------|--|-----|-----|-----|-----|------|
| Symbol                 | Parameter                        | Conditions   |     | Min | Тур | Max | Unit |
| V <sub>DS</sub>        | drain-source voltage             | T <sub>j</sub> = 25 °C   |     | -   | -   | 20  | V    |
| V <sub>GS</sub>        | gate-source voltage              | -  |     | -8  | -   | 8   | V    |
| I <sub>D</sub>         | drain current                    | $V_{GS}$ = 4.5 V; $T_{amb}$ = 25 °C; t ≤ 5 s                   | [1] | -   | -   | 2.2 | А    |
| Static characteristics |                                  |  |     |     |     |     |      |
| R <sub>DSon</sub>      | drain-source on-state resistance | $V_{GS}$ = 4.5 V; I <sub>D</sub> = 2 A; T <sub>j</sub> = 25 °C |     | -   | 57  | 65  | mΩ   |

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm<sup>2</sup>.

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# 5. Pinning information

| Table 2. | Pinning | information |                       |                     |
|----------|---------|-------------|-----------------------|---------------------|
| Pin      | Symbol  | Description | Simplified outline    | Graphic symbol      |
| 1        | G       | gate        | 3                     | D                   |
| 2        | S       | souce       |                       |                     |
| 3        | D       | drain       | 1 2<br>SC-70 (SOT323) | G<br>S<br>017aaa255 |

# 6. Ordering information

| Table 3. Ordering information |       |  |         |  |  |  |
|-------------------------------|-------|--|---------|--|--|--|
| Type number Package           |       |  |         |  |  |  |
|                               | Name  | Description                              | Version |  |  |  |
| PMF63UNE                      | SC-70 | plastic surface-mounted package; 3 leads | SOT323  |  |  |  |

# 7. Marking

| Table 4. Marking codes |              |
|------------------------|--------------|
| Type number            | Marking code |
|                        | [1]          |
| PMF63UNE               | Z%V          |

[1] % = placeholder for manufacturing site code

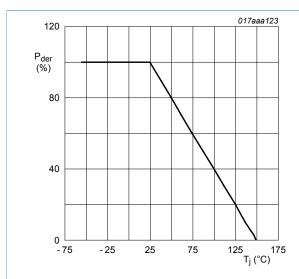
### 8. Limiting values

#### Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol           | Parameter               | Conditions  |     | Min | Max  | Unit |
|------------------|-------------------------|---|-----|-----|------|------|
| V <sub>DS</sub>  | drain-source voltage    | T <sub>j</sub> = 25 °C                                |     | -   | 20   | V    |
| V <sub>GS</sub>  | gate-source voltage     |   |     | -8  | 8    | V    |
| I <sub>D</sub>   | drain current           | $V_{GS}$ = 4.5 V; $T_{amb}$ = 25 °C; t ≤ 5 s          | [1] | -   | 2.2  | А    |
|                  |                         | V <sub>GS</sub> = 4.5 V; T <sub>amb</sub> = 25 °C     | [1] | -   | 2    | А    |
|                  |                         | V <sub>GS</sub> = 4.5 V; T <sub>amb</sub> = 100 °C    | [1] | -   | 1.3  | А    |
| I <sub>DM</sub>  | peak drain current      | $T_{amb}$ = 25 °C; single pulse; $t_p \le 10 \ \mu s$ |     | -   | 8    | А    |
| P <sub>tot</sub> | total power dissipation | T <sub>amb</sub> = 25 °C                              | [2] | -   | 300  | mW   |
|                  |                         |   | [1] | -   | 395  | mW   |
|                  |                         | T <sub>sp</sub> = 25 °C                               |     | -   | 1.8  | W    |
| Tj               | junction temperature    |   |     | -55 | 150  | °C   |
| T <sub>amb</sub> | ambient temperature     |   |     | -55 | 150  | °C   |
| T <sub>stg</sub> | storage temperature     |   |     | -65 | 150  | °C   |
| I <sub>S</sub>   | source current          | T <sub>amb</sub> = 25 °C                              | [1] | -   | 0.37 | А    |

Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm<sup>2</sup>.
Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper; tin-plated and standard footprint.





$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100 \%$$

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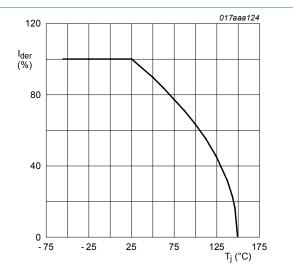
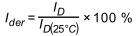
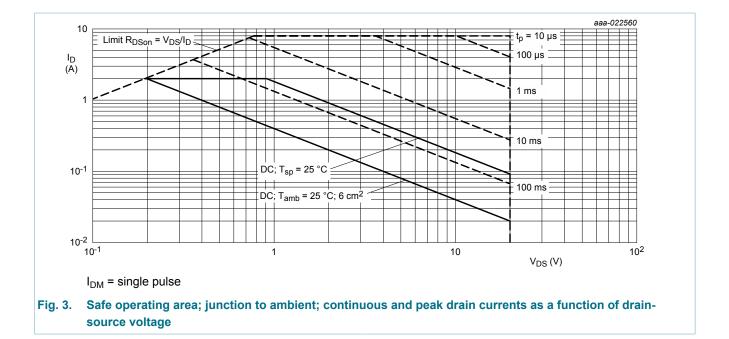


Fig. 2. Normalized continuous drain current as a function of junction temperature



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### 9. Thermal characteristics

| Table 6.   | Thermal characteristics                                |                      |     |     |     |     |      |
|--|--|----------------------|-----|-----|-----|-----|------|
| Symbol   | Parameter  | Conditions           |     | Min | Тур | Max | Unit |
| R <sub>th(j-a)</sub> thermal resistance<br>from junction to<br>ambient |  |                      | [1] | -   | 363 | 418 | K/W  |
|  | •  |                      | [2] | -   | 276 | 317 | K/W  |
|  | ampient  | in free air; t ≤ 5 s | [2] | -   | 238 | 273 | K/W  |
| R <sub>th(j-sp)</sub>  | thermal resistance<br>from junction to solder<br>point |                      |     | -   | 60  | 69  | K/W  |

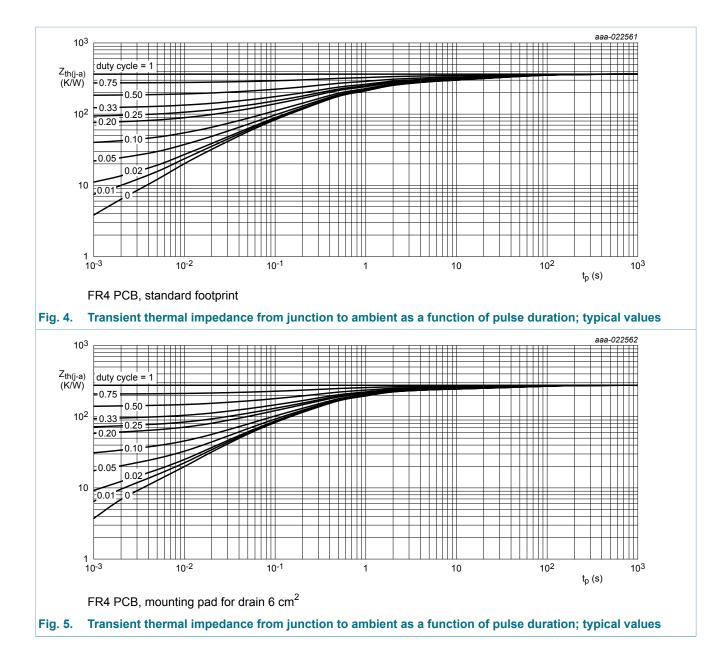
[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper; tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm<sup>2</sup>.

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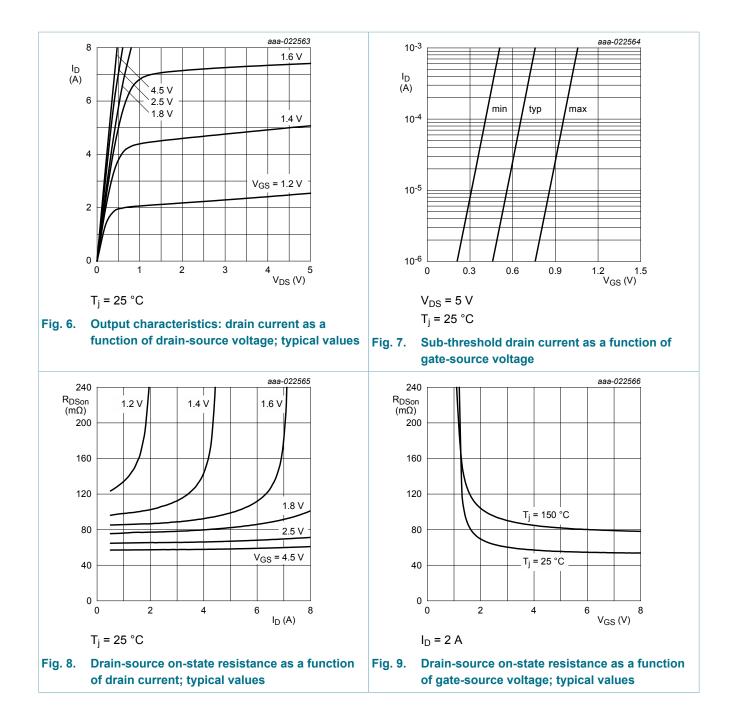
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# **10. Characteristics**

| Symbol               | Parameter                         | Conditions   | Min  | Тур | Max  | Unit |
|----------------------|-----------------------------------|--|------|-----|------|------|
| Static chara         | octeristics                       |  |      |     |      |      |
| V <sub>(BR)DSS</sub> | drain-source<br>breakdown voltage | $I_D$ = 250 µA; $V_{GS}$ = 0 V; $T_j$ = 25 °C                          | 20   | -   | -    | V    |
| V <sub>GSth</sub>    | gate-source threshold voltage     | $I_D$ = 250 µA; $V_{DS}$ = $V_{GS}$ ; $T_j$ = 25 °C                    | 0.45 | 0.7 | 1    | V    |
| I <sub>DSS</sub>     | drain leakage current             | $V_{DS}$ = 20 V; $V_{GS}$ = 0 V; $T_j$ = 25 °C                         | -    | -   | 1    | μA   |
| I <sub>GSS</sub>     | gate leakage current              | V <sub>GS</sub> = 8 V; T <sub>j</sub> = 25 °C                          | -    | -   | 10   | μA   |
|                      |                                   | $V_{GS}$ = -8 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C                         | -    | -   | -10  | μA   |
|                      |                                   | $V_{GS}$ = 4.5 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C                        | -    | -   | 5    | μA   |
|                      |                                   | $V_{GS}$ = -4.5 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C                       | -    | -   | -5   | μA   |
| DOON                 | drain-source on-state             | $V_{GS}$ = 4.5 V; I <sub>D</sub> = 2 A; T <sub>j</sub> = 25 °C         | -    | 57  | 65   | mΩ   |
|                      | resistance                        | $V_{GS}$ = 4.5 V; I <sub>D</sub> = 2 A; T <sub>j</sub> = 150 °C        | -    | 84  | 96   | mΩ   |
|                      |                                   | $V_{GS}$ = 2.5 V; I <sub>D</sub> = 1.8 A; T <sub>j</sub> = 25 °C       | -    | 64  | 74   | mΩ   |
|                      |                                   | $V_{GS}$ = 1.8 V; I <sub>D</sub> = 0.8 A; T <sub>j</sub> = 25 °C       | -    | 78  | 88   | mΩ   |
| 9 <sub>fs</sub>      | forward<br>transconductance       | V <sub>DS</sub> = 5 V; I <sub>D</sub> = 2 A; T <sub>j</sub> = 25 °C    | -    | 9   | -    | S    |
| R <sub>G</sub>       | gate resistance                   | f = 1 MHz; T <sub>j</sub> = 25 °C                                      | -    | 1.8 | -    | Ω    |
| Dynamic ch           | aracteristics                     |  |      |     |      |      |
| Q <sub>G(tot)</sub>  | total gate charge                 | $V_{DS}$ = 10 V; I <sub>D</sub> = 2 A; V <sub>GS</sub> = 4.5 V;        | -    | 3.9 | 5.85 | nC   |
| Q <sub>GS</sub>      | gate-source charge                | T <sub>j</sub> = 25 °C   | -    | 0.3 | -    | nC   |
| Q <sub>GD</sub>      | gate-drain charge                 |  | -    | 0.9 | -    | nC   |
| C <sub>iss</sub>     | input capacitance                 | $V_{DS}$ = 10 V; f = 1 MHz; $V_{GS}$ = 0 V;                            | -    | 289 | -    | pF   |
| C <sub>oss</sub>     | output capacitance                | T <sub>j</sub> = 25 °C   | -    | 51  | -    | pF   |
| C <sub>rss</sub>     | reverse transfer capacitance      |  | -    | 42  | -    | pF   |
| t <sub>d(on)</sub>   | turn-on delay time                | $V_{DS}$ = 10 V; I <sub>D</sub> = 2 A; V <sub>GS</sub> = 4.5 V;        | -    | 8   | -    | ns   |
| t <sub>r</sub>       | rise time                         | R <sub>G(ext)</sub> = 6 Ω; T <sub>j</sub> = 25 °C                      | -    | 27  | -    | ns   |
| t <sub>d(off)</sub>  | turn-off delay time               |  | -    | 35  | -    | ns   |
| t <sub>f</sub>       | fall time                         |  | -    | 19  | -    | ns   |
| Source-drai          | n diode                           |  | I    |     |      |      |
| V <sub>SD</sub>      | source-drain voltage              | I <sub>S</sub> = 0.37 A; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C | -    | 0.7 | 1.2  | V    |

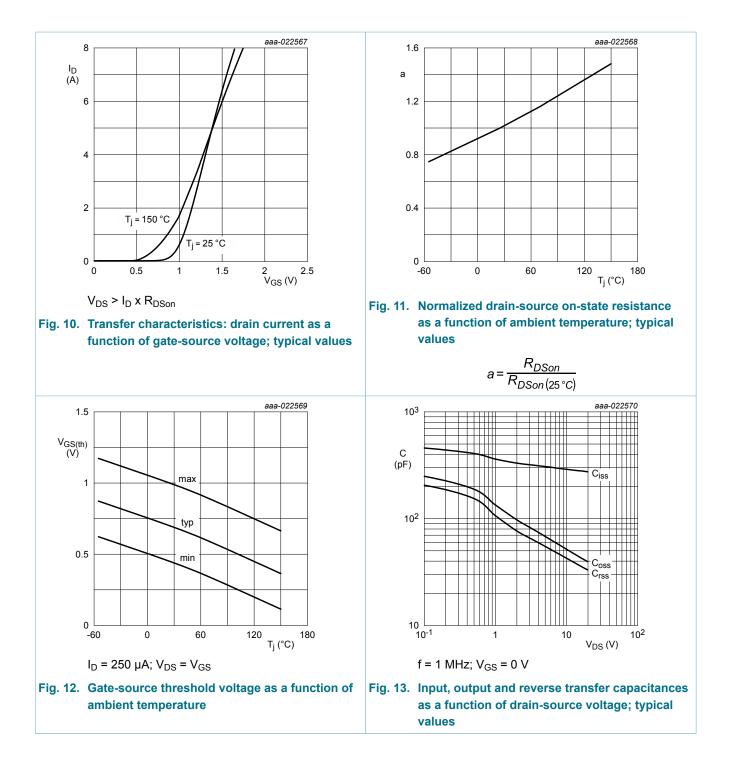
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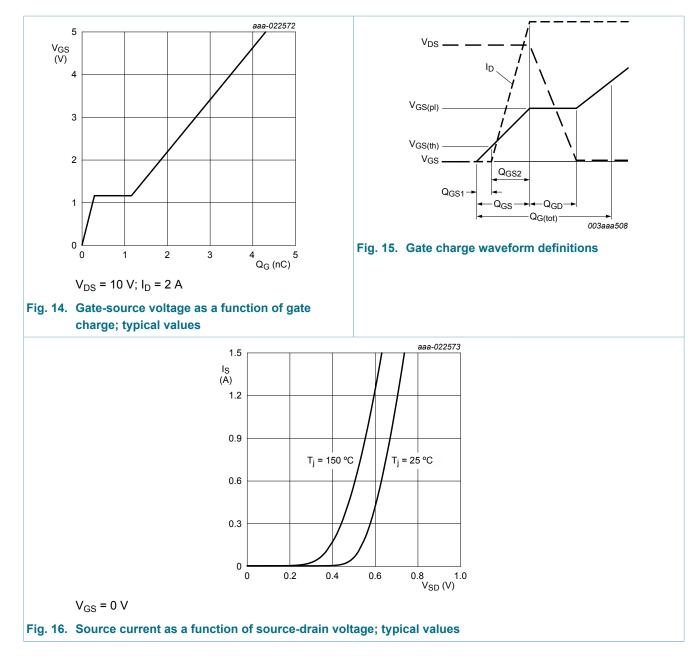
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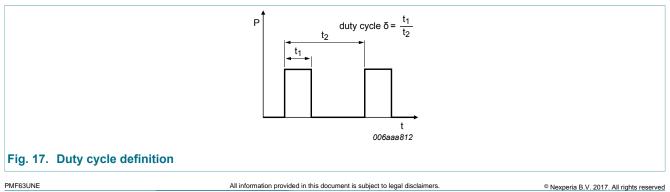
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### **11. Test information**



### 12. Package outline

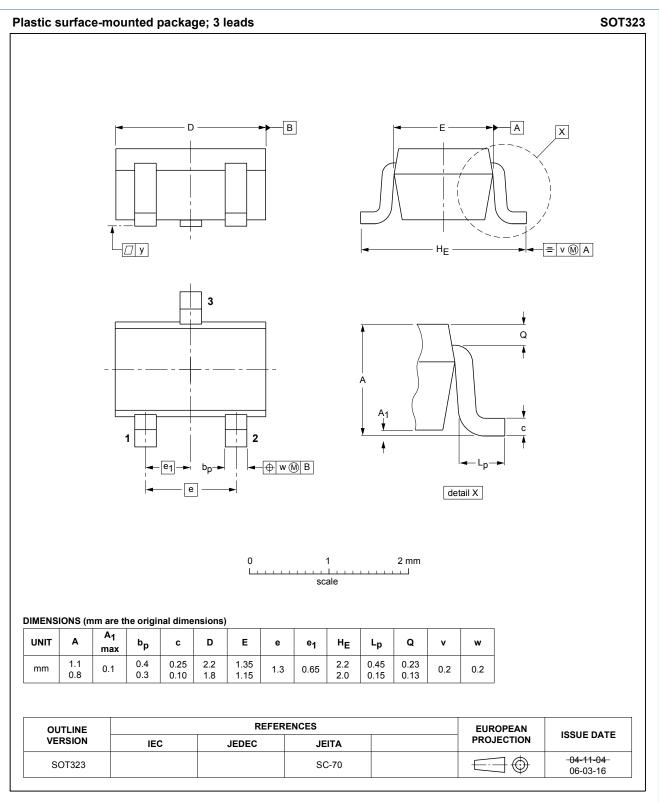
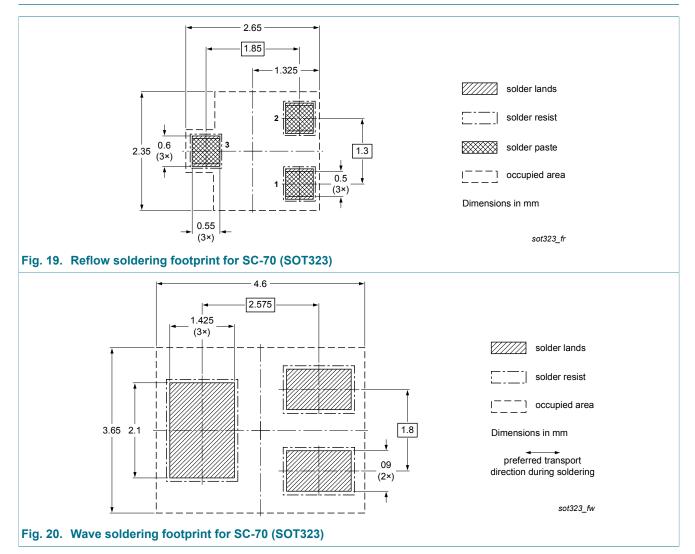


Fig. 18. Package outline SC-70 (SOT323)

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### 13. Soldering



# 14. Revision history

| Table 8. Revision his | ble 8. Revision history |                    |               |            |  |  |  |
|-----------------------|-------------------------|--------------------|---------------|------------|--|--|--|
| Data sheet ID         | Release date            | Data sheet status  | Change notice | Supersedes |  |  |  |
| PMF63UNE v.1          | 20160420                | Product data sheet | -             | -          |  |  |  |

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|--------------------------------------|-----------------------|---|
| Objective<br>[short] data<br>sheet   | Development           | This document contains data from<br>the objective specification for product<br>development. |
| Preliminary<br>[short] data<br>sheet | Qualification         | This document contains data from the preliminary specification.                             |
| Product<br>[short] data<br>sheet     | Production            | This document contains the product specification.   |

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